

	Type	Hits	Search Text	DBs	Time Stamp
1	BRS	1	tunnel\$4 adj voltage with metal near2 contamin\$5	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/27 12:53
2	IS& R	2	("6255128").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/22 08:45
3	BRS	3	("4812756" "5216362" "6011404").PN.	USPAT	2003/01/22 08:45
4	BRS	6	(COS or corona) with metal near2 contamin\$5	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/22 09:40
5	BRS	24	mobile adj ion adj density	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/22 09:16
6	BRS	20	mobile adj ion with anneal\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/22 09:34
7	BRS	9	("4978915" "4980301" "5275687" "5519334" "5773989" "5804981" "5963783" "6011404" "6073501").PN.	USPAT	2003/01/22 09:19
8	IS& R	2	("5963783").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/22 09:35
9	BRS	4215 4	(drive or driving) with (metal or contamin\$8)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/22 09:57
10	BRS	1332 86	(COS or corona) or SPV or surface adj photo\$10	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/22 09:56
11	BRS	1149 89	(COS or corona) or SPV or surface adj photovoltage	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/27 15:27

	Type	Hits	Search Text	DBs	Tim Stamp
12	BRS	582	((drive or driving) with (metal or contamin\$8)) and ((COS or corona) or SPV or surface adj photovoltage)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/22 09:57
13	BRS	1665 1	(drive or driving) near5 (metal or contamin\$8)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/22 09:58
14	BRS	253	((COS or corona) or SPV or surface adj photovoltage) and ((drive or driving) near5 (metal or contamin\$8))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/27 15:01
15	IS& R	29	(("4599558") or ("4812756") or ("5485091") or ("5594247") or ("5644223") or ("5650731") or ("5661408") or ("5742658") or ("5767693") or ("5852232") or ("5866806") or ("5948972") or ("5955661") or ("6011404") or ("6191605") or ("6202029") or ("6267005") or ("3495269") or ("6496352") or ("4734721") or ("5834941") or ("6060709") or ("6072320") or ("6091257") or ("6097196") or ("6104206") or ("6121783") or ("6201999") or ("6224638")) .PN.	USPAT	2003/01/22 11:27

	Type	Hits	Search T xt	DBs	Time Stamp
16	BRS	15	((("4599558") or ("4812756") or ("5485091") or ("5594247") or ("5644223") or ("5650731") or ("5661408") or ("5742658") or ("5767693") or ("5852232") or ("5866806") or ("5948972") or ("5955661") or ("6011404") or ("6191605") or ("6202029") or ("6267005") or ("3495269") or ("6496352") or ("4734721") or ("5834941") or ("6060709") or ("6072320") or ("6091257") or ("6097196") or ("6104206") or ("6121783") or ("6201999") or ("6224638")).PN.) and (heat\$3 or thermal\$2 or anneal\$4)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/22 10:46

	Type	Hits	Search Text	DBs	Time Stamp
17	BRS	1	((("4599558") or ("4812756") or ("5485091") or ("5594247") or ("5644223") or ("5650731") or ("5661408") or ("5742658") or ("5767693") or ("5852232") or ("5866806") or ("5948972") or ("5955661") or ("6011404") or ("6191605") or ("6202029") or	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/22 11:32
			("6267005") or ("3495269") or ("6496352") or ("4734721") or ("5834941") or ("6060709") or ("6072320") or ("6091257") or ("6097196") or ("6104206") or ("6121783") or ("6201999") or ("6224638")).PN.) and tunnel\$4 adj voltage		
18	BRS	194	tunneling adj voltage	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/22 13:50
19	IS& R	2	("20020047184").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/28 12:41
20	BRS	93	carrier adj medium.clm. with program adj instructions.clm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/27 12:56
21	BRS	176	anneal\$3.clm. with control.clm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/27 13:01

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22	BRS	71	wafer\$1 near3 (qualifying or qualification)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/27 13:31
23	IS& R	6	(("4567431") or ("5025145") or ("5471293")).PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/27 13:32
24	BRS	51	heavy adj metal\$1 and (surface adj photovoltage or SPV)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/27 13:48
25	BRS	1040	anneal\$4 near3 "200"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/27 13:52
26	BRS	380	anneal\$4 near3 "200" and semiconductor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/27 13:53
27	BRS	2	anneal\$4 with heating adj chuck	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/27 13:54
28	BRS	72	anneal\$4 with chuck	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/27 14:02
29	BRS	1549	controller adj software	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/27 14:03
30	BRS	5791	computer adj executable	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/27 14:03
31	BRS	34	(controller adj software) and (computer adj executable)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/27 14:06

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32	BRS	275	controller with wafer and computer with software	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/27 14:16
33	BRS	6	controller with wafer and computer with software with media	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/27 14:39
34	IS& R	2	("6168672").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/27 14:23
35	BRS	1	wafer\$1 near3 reject\$3 with sodium	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/27 14:50
36	BRS	1	wafer\$1 near3 reject\$3 and sodium near5 measur\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/27 14:50
37	BRS	1	wafer\$1 near3 reject\$3 and sodium near5 measur\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/27 14:53
38	BRS	1	wafer\$1 near3 reject\$3 and mobile adj ion	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/27 14:55
39	BRS	126	wafer\$1 near3 reject\$3 and contamination	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/27 14:58
40	BRS	4	wafer\$1 near3 reject\$3 and heavy adj metal\$1	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/27 14:55
41	BRS	13	wafer\$1 near3 inspect\$3 same (mobile adj ion\$1 or sodium or potassium or iron)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/27 15:00

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42	BRS	3	((COS or corona) or SPV or surface adj photovoltage) and ((drive or driving) near5 (metal or contamin\$8)) and reject\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/27 15:03
43	BRS	28	((COS or corona) or SPV or surface adj photovoltage) and ((drive or driving) near5 (metal or contamin\$8)) and tolerance	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/27 15:05
44	BRS	70	((COS or corona) or SPV or surface adj photovoltage) and (metal or contamin\$8) with tolerance	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/27 15:06
45	BRS	1269 5	((COS or corona) or SPV or surface adj photovoltage) and copper	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/27 15:28
46	BRS	584	((COS or corona) or SPV or surface adj photovoltage) and copper and wafer	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/27 15:31
47	BRS	178	((COS with corona) or corona adj discharge) or SPV or surface adj photovoltage) and copper and wafer	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/27 16:02
48	BRS	408	(sodium or mobile adj ion) with tolerance\$1	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/27 16:03
49	BRS	7	(sodium or mobile adj ion) with tolerance\$1 and wafer\$1	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/27 16:03
50	BRS	247	corona adj discharge same oven	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/28 10:44

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51	BRS	3313	corona adj discharge and (oven or furnace)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/28 10:45
52	BRS	0	corona adj discharge and (oven or furnace) and (surface adj photovoltage)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/28 10:45
53	BRS	3313	corona adj discharge and (oven or furnace)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/28 10:46
54	BRS	0	corona adj discharge and (oven or furnace) and (SPV)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/28 10:46
55	BRS	3317	(corona adj discharge or corona with COS) and (oven or furnace)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/28 10:46
56	BRS	1	(corona adj discharge or corona with COS) and (oven or furnace) and (spv or surface adj photovoltage)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/28 10:47
57	IS& R	2	("20020090746").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/28 18:37
58	BRS	2	corona adj oxide adj silicon	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/28 14:03
59	BRS	19	corona adj oxide	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/28 12:52
60	BRS	0	(corona adj oxide) and tolerance	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/28 12:52

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61	BRS	18	corona adj oxide adj semiconductor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/28 16:30
62	BRS	2773	sodium with screen\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/28 12:56
63	BRS	0	(corona adj oxide adj semiconductor) and (sodium with screen\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/28 13:00
64	IS& R	2	("3946415").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/28 13:31
65	BRS	18	(corona adj oxide adj silicon) or (corona adj oxide adj semiconductor)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/28 14:03
66	BRS	7	((corona adj oxide adj silicon) or (corona adj oxide adj semiconductor)) and tunnel\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/28 14:39
67	IS& R	2	("6011404").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/28 15:24
68	BRS	23	capacitance-voltage with impurity	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/28 16:26
69	BRS	21	non-destructive adj testing with iron	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/28 16:26
70	BRS	0	(corona adj oxide adj semiconductor) and reference adj wafer	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/28 16:30

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71	BRS	0	(corona adj oxide adj semiconductor) and reference adj oxide	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/28 16:30
72	BRS	16	(corona adj oxide adj semiconductor) and reference	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/29 07:59
73	IS& R	148	(438/529).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/01/29 07:59
74	IS& R	2	("5773989").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/13 16:53
75	IS& R	2	("5887363").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/13 16:54
76	IS& R	2	((("6011404") or ("5773989")).PN.	USPAT	2003/05/27 15:13
77	IS& R	2	("20020011623").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/27 15:15
78	BRS	22	metal adj contamination with anneal\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/27 15:25
79	BRS	12	metal adj contamination with furnace and anneal\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/27 16:03
80	BRS	64	metal adj contamination with (insulat\$3 or dielectric) and anneal\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/27 16:03
81	BRS	777	iron with (insulat\$3 or dielectric) and anneal\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/27 16:06

	Type	Hits	Search Text	DBs	Time Stamp
82	BRS	3	iron with (insulat\$3 or dielectric) with gate and anneal\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/27 17:03
83	BRS	8171	anneal\$4 and COS	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/28 08:52
84	IS& R	2	("6011404").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/27 18:22
85	BRS	863	anneal\$4 and corona adj2 (oxide or discharge)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/28 16:16
86	BRS	70	anneal\$4 and corona adj2 (oxide or discharge) and tunnel\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/28 08:58
87	BRS	11	tunnel\$4 with contamination near5 (metal\$1 or copper or cu or iron or fe)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/28 09:14
88	BRS	1	tunneling adj voltage adj measurement	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/28 16:15
89	BRS	2491	ammonia and corona adj2 (oxide or discharge)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/28 16:17
90	BRS	1074	ammonia and corona adj2 (oxide or discharge) and (semiconductor or silicon)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/28 16:36
91	BRS	108	ammonia and corona adj2 (oxide or discharge) and (semiconductor or silicon) and particulate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/28 16:37

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92	BRS	124	ammonia and corona adj2 (oxide or discharge) and (semiconductor or silicon) and particulate\$1	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/28 16:41
93	BRS	207	corona adj2 (oxide or discharge) with particulate\$1	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/28 16:50
94	BRS	0	thermal adj stress with mobile adj ions	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/28 16:51
95	BRS	0	thermal adj stress with mobile adj ion\$1	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/28 16:51
96	BRS	66	(thermal or heat) with mobile adj ion\$1	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/28 16:52
97	BRS	134	(thermal or heat\$3) with mobile adj ion\$1	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/28 17:04
98	IS& R	1	("20020135005").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/28 18:37
99	BRS	112	temperature near3 bias near3 stress	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/30 15:09
100	BRS	24	temperature near3 bias near3 stress with (oxide or insulat\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/30 16:16